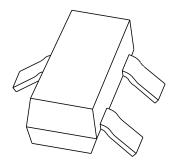
DISCRETE SEMICONDUCTORS

DATA SHEET



BAS55 High-speed diode

Product specification Supersedes data of November 1993 File under Discrete Semiconductors, SC01 1996 Apr 23





High-speed diode

BAS55

FEATURES

- Small plastic SMD package
- High switching speed: max. 6 ns
- Continuous reverse voltage: max. 60 V
- Repetitive peak reverse voltage: max. 60 V
- Repetitive peak forward current: max. 600 mA
- Forward voltage: max. 1 V.

APPLICATIONS

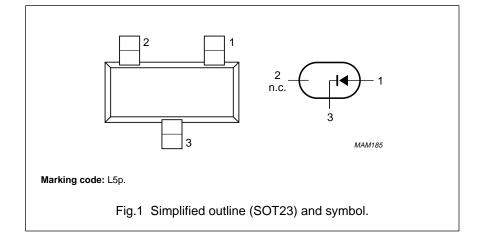
 High-speed switching in surface mounted circuits.

DESCRIPTION

The BAS55 is a high-speed switching diode fabricated in planar technology, and encapsulated in the small rectangular plastic SMD SOT23 package.

PINNING

PIN	DESCRIPTION
1	anode
2	not connected
3	cathode



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{RRM}	repetitive peak reverse voltage		_	60	V
V _R	continuous reverse voltage		_	60	V
I _F	continuous forward current	see Fig.2; note 1	_	250	mA
I _{FRM}	repetitive peak forward current		_	600	mA
I _{FSM}	non-repetitive peak forward current	square wave; T _j = 25 °C prior to surge; see Fig.4			
		t = 1 μs	_	9	A
		t = 100 μs	_	3	A
		t = 10 ms	_	1.7	A
P _{tot}	total power dissipation	T _{amb} = 25 °C; note 1	_	250	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C

Note

1. Device mounted on an FR4 printed-circuit board.

High-speed diode

BAS55

ELECTRICAL CHARACTERISTICS

 $T_i = 25$ °C; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _F	forward voltage	see Fig.3; I _F = 200 mA; DC value; note 1	_	1.0	V
I _R	reverse current	see Fig.5			
		V _R = 60 V	_	100	nA
		V _R = 60 V; T _j = 150 °C	-	100	μΑ
C_d	diode capacitance	$f = 1 \text{ MHz}$; $V_R = 0$; see Fig.6	_	2.5	pF
t _{rr}	reverse recovery time	when switched from I_F = 400 mA to I_R = 400 mA; R_L = 100 Ω ; measured at I_R = 40 mA; see Fig.7	-	6	ns
V _{fr}	forward recovery voltage	when switched to $I_F = 400$ mA; $t_r = 30$ ns; see Fig.8	_	2	V
		when switched to $I_F = 400$ mA; $t_r = 100$ ns; see Fig.8	_	1.5	V

Note

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-tp}	thermal resistance from junction to tie-point		330	K/W
R _{th j-a}	thermal resistance from junction to ambient	note 1	500	K/W

Note

1. Device mounted on an FR4 printed-circuit board.

^{1.} T_{amb} = 25 °C; device has reached the thermal equilibrium when mounted on an FR4 printed-circuit board.

High-speed diode

BAS55

GRAPHICAL DATA

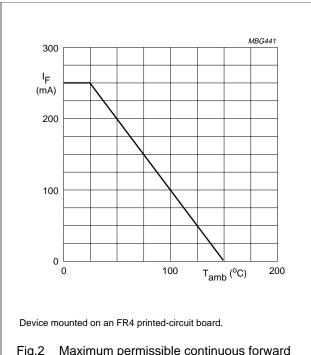


Fig.2 Maximum permissible continuous forward current as a function of ambient temperature.

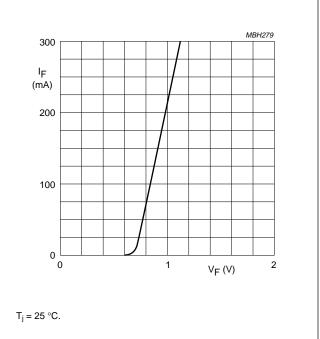
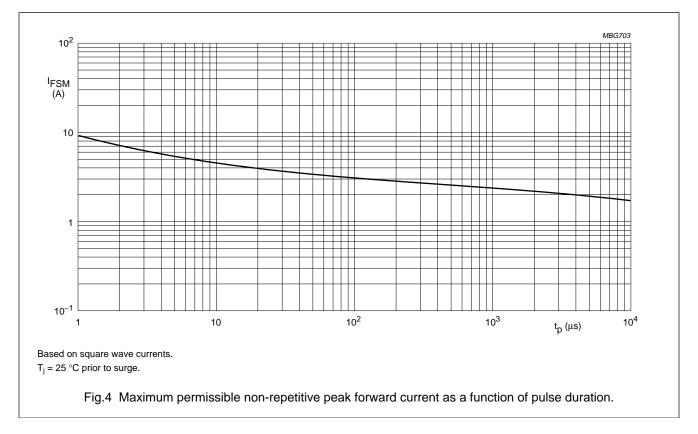
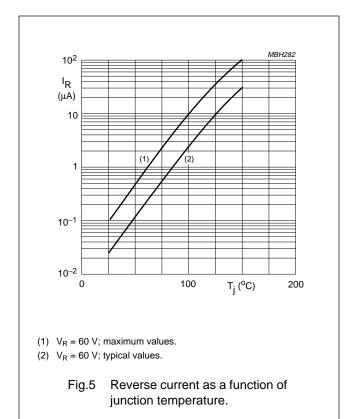


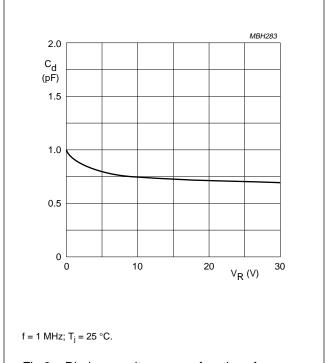
Fig.3 Forward current as a function of forward voltage; typical values.



High-speed diode

BAS55



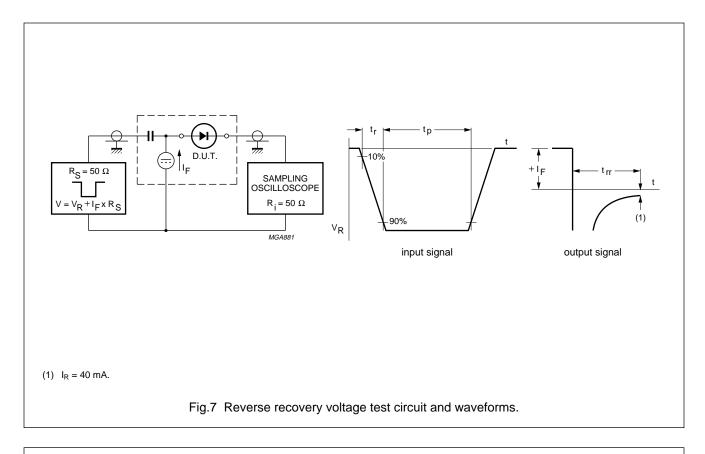


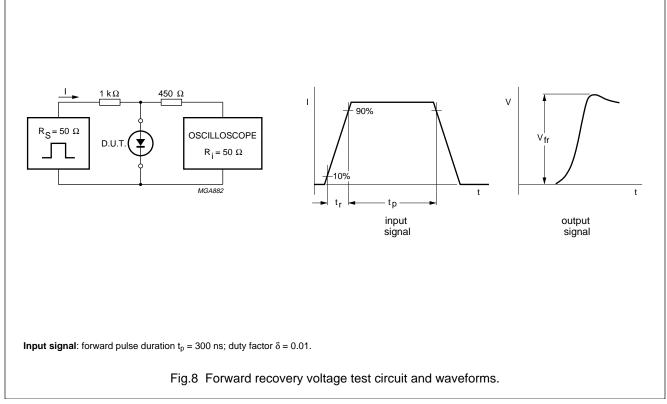
1996 Apr 23

5

High-speed diode

BAS55

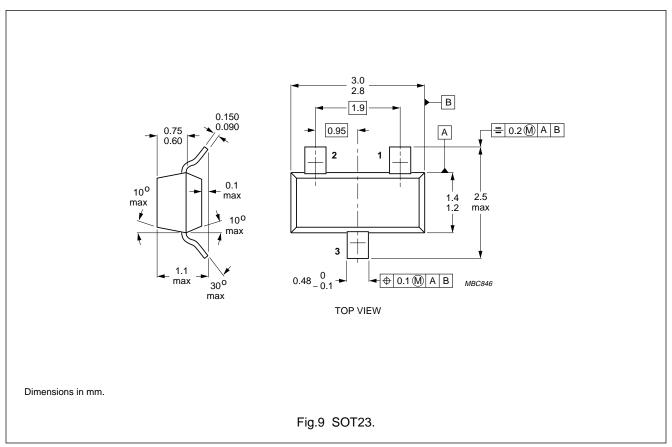




High-speed diode

BAS55

PACKAGE OUTLINE



DEFINITIONS

Data Sheet Status			
Objective specification	This data sheet contains target or goal specifications for product development.		
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.		
Product specification	This data sheet contains final product specifications.		
Limiting values			
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.			
Application information			
Where application information is given, it is advisory and does not form part of the specification.			

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.